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## BYW29ED-200,118

WeEn Semiconductors

Rectifiers TAPE13 REC-EPI

Any questions, please feel free to contact us. info@kaimte.com



### 1. Global joint venture starts operations as WeEn Semiconductors

Dear customer,

As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

In this document where the previous NXP references remain, please use the new links as shown below.

WWW - For www.nxp.com use www.ween-semi.com

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Thank you for your cooperation and understanding,

WeEn Semiconductors



## DISCRETE SEMICONDUCTORS

# DATA SHEET

## BYW29EB, BYW29ED series Rectifier diodes ultrafast, rugged

**Product specification** 

November 1998



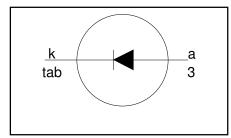
### **Rectifier diodes** ultrafast, rugged

### BYW29EB, BYW29ED series

### **FEATURES**

- · Low forward volt drop
- Fast switchingSoft recovery characteristic
- Reverse surge capability
  High thermal cycling performance
  Low thermal resistance

### **SYMBOL**



### **QUICK REFERENCE DATA**

$$V_{R} = 150 \text{ V}/200 \text{ V}$$

$$V_{F} \leq 0.895 \text{ V}$$

$$I_{F(AV)} = 8 \text{ A}$$

$$I_{RRM} = 0.2 \text{ A}$$

$$t_{rr} \leq 25 \text{ ns}$$

### **GENERAL DESCRIPTION**

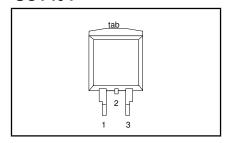
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYW29EB series is supplied in the SOT404 surface mounting package. The BYW29ED series is supplied in the SOT428 surface mounting package.

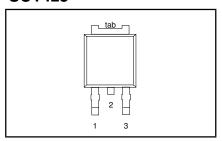
### **PINNING**

| PIN | DESCRIPTION          |  |  |
|-----|----------------------|--|--|
| 1   | no connection        |  |  |
| 2   | cathode <sup>1</sup> |  |  |
| 3   | anode                |  |  |
| tab | cathode              |  |  |

### **SOT404**



### **SOT428**



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| SYMBOL             | PARAMETER                                 | CONDITIONS  | MIN.  | N. MAX. |        | UNIT   |
|--------------------|---|---|-------|---------|--------|--------|
|                    |   | BYW29EB/ BYW29ED  |       | -150    | -200   |        |
| $V_{RRM}$          | Peak repetitive reverse voltage           |   | -     | 150     | 200    | V      |
| $V_{RWM}$          | Working peak reverse voltage              |   | -     | 150     | 200    | V      |
| $V_R$              | Continuous reverse voltage                |   | -     | 150     | 200    | _ v    |
| I <sub>F(AV)</sub> | Average rectified forward current         | square wave; $\delta = 0.5$ ; $T_{mb} \le 128$ °C                           | -     | 8       | 3      | A      |
| I <sub>FRM</sub>   | Repetitive peak forward current           | square wave; $\delta = 0.5$ ; $T_{mb} \le 128$ °C                           | -     | 1       | 6      | Α      |
| I <sub>FSM</sub>   | Non-repetitive peak forward current       | t = 10 ms<br>t = 8.3 ms<br>sinusoidal; with reapplied V <sub>RRM(max)</sub> | -     |         | 0<br>8 | A<br>A |
| I <sub>RRM</sub>   | Peak repetitive reverse surge current     | $t_p = 2 \mu s; \delta = 0.001$   | -     | 0       | .2     | A      |
| I <sub>RSM</sub>   | Peak non-repetitive reverse surge current | $t_p = 100 \ \mu s$   | -     | 0       | .2     | Α      |
| T <sub>j</sub>     | Operating junction temperature            |   | - 150 |         | 50     | °C     |
| T <sub>sta</sub>   | Storage temperature                       |   | - 40  | 15      | 50     | l °C   |

1. It is not possible to make connection to pin 2 of the SOT428 or SOT404 packages.

NXP Semiconductors Product specification

Rectifier diodes ultrafast, rugged

BYW29EB, BYW29ED series

### **ESD LIMITING VALUE**

| SYMBOL         | PARAMETER                                 | CONDITIONS                                  | MIN. | MAX. | UNIT |
|----------------|---|---|------|------|------|
| V <sub>C</sub> | Electrostatic discharge capacitor voltage | Human body model;<br>C = 250 pF; R = 1.5 kΩ | -    | 8    | kV   |

### THERMAL RESISTANCES

| SYMBOL               | PARAMETER   | CONDITIONS  | MIN. | TYP. | MAX. | UNIT |
|----------------------|---|---|------|------|------|------|
| R <sub>th j-mb</sub> | Thermal resistance junction                             |   | -    | -    | 2.7  | K/W  |
| R <sub>th i-a</sub>  | to mounting base Thermal resistance junction to ambient | SOT404 and SOT428 packages, pcb mounted, minimum footprint, FR4 board | -    | 50   | -    | K/W  |

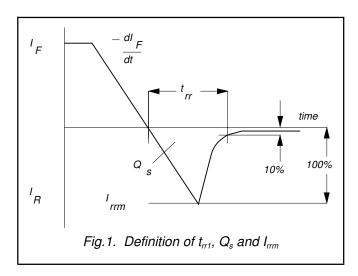
### **ELECTRICAL CHARACTERISTICS**

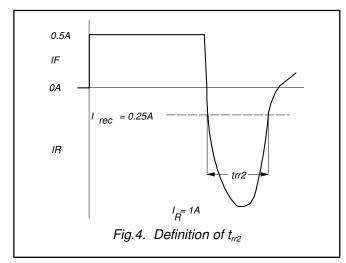
T<sub>i</sub> = 25 °C unless otherwise specified

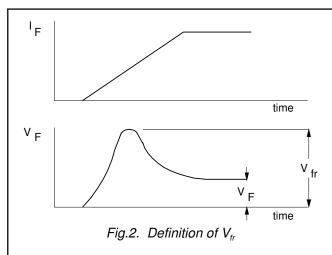
| )  |  |  |       |                    |                  |                     |
|--|--|--|-------|--------------------|------------------|---------------------|
| SYMBOL   | PARAMETER  | CONDITIONS   | MIN.  | TYP.               | MAX.             | UNIT                |
| V <sub>F</sub>   | Forward voltage  | $I_F = 8 \text{ A}; T_j = 150^{\circ}\text{C}$<br>$I_F = 8 \text{ A}$  | -     | 0.8<br>0.92        | 0.895<br>1.05    | V                   |
| I <sub>R</sub>   | Reverse current  | $I_{F}^{i} = 20 \text{ A}$ $V_{R} = V_{RWM}$ $V_{R} = V_{RWM}^{i}$ $V_{R} = V_{RWM}^{i}$ $V_{R} = V_{RWM}^{i}$   | -     | 1.1<br>2<br>0.2    | 1.3<br>10<br>0.6 | V<br>μA<br>mA       |
| $\begin{matrix} Q_{rr} \\ t_{rr1} \\ t_{rr2} \\ V_{fr} \end{matrix}$ | Reverse recovered charge<br>Reverse recovery time<br>Reverse recovery time<br>Forward recovery voltage | $\begin{array}{l} I_F = 2 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 1 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 100 \text{ A/}\mu\text{s} \\ I_F = 0.5 \text{ A to } I_R = 1 \text{ A; } I_{rec} = 0.25 \text{ A} \\ I_F = 1 \text{ A; } dI_F/dt = 10 \text{ A/}\mu\text{s} \end{array}$ | 1 1 1 | 4<br>20<br>15<br>1 | 11<br>25<br>20   | nC<br>ns<br>ns<br>V |

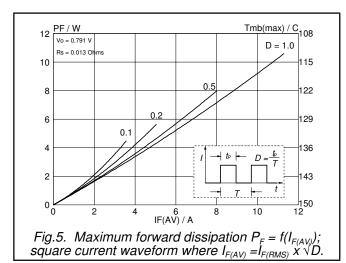
## Rectifier diodes ultrafast, rugged

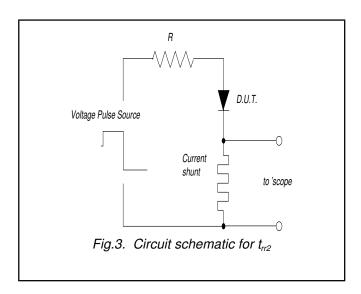
## BYW29EB, BYW29ED series











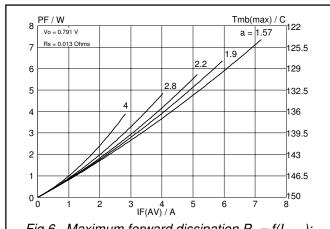
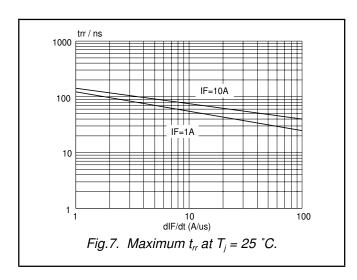
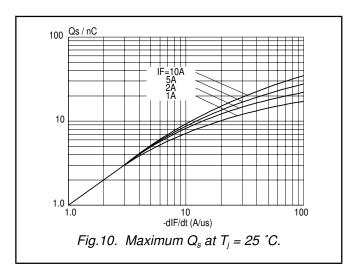


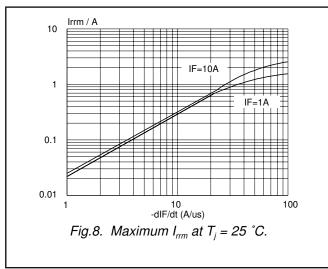
Fig.6. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = form factor =  $I_{F(RMS)} / I_{F(AV)}$ .

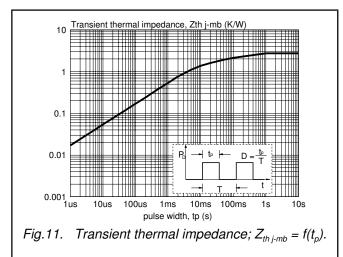
## Rectifier diodes ultrafast, rugged

### BYW29EB, BYW29ED series









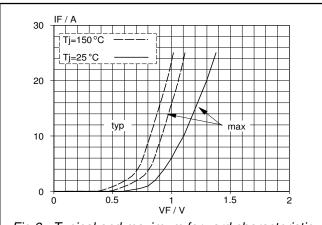


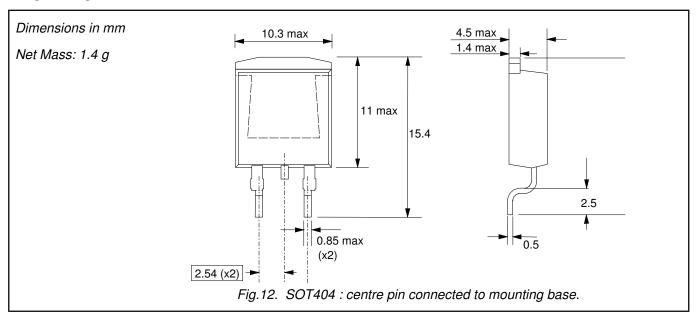
Fig.9. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

NXP Semiconductors Product specification

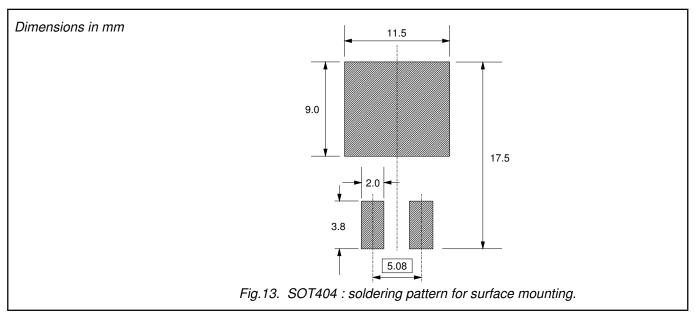
Rectifier diodes ultrafast, rugged

### BYW29EB, BYW29ED series

### **MECHANICAL DATA**



### **MOUNTING INSTRUCTIONS**



### **Notes**

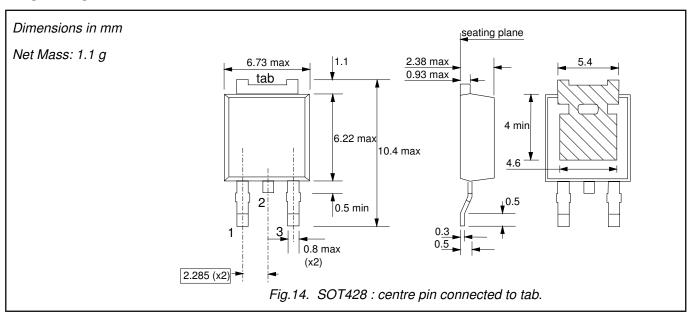
1. Epoxy meets UL94 V0 at 1/8".

NXP Semiconductors Product specification

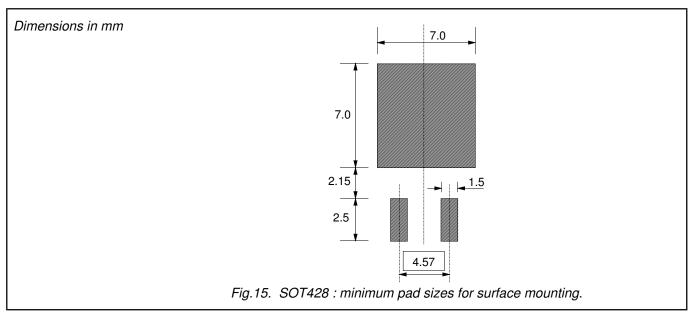
Rectifier diodes ultrafast, rugged

### BYW29EB, BYW29ED series

### **MECHANICAL DATA**



### **MOUNTING INSTRUCTIONS**



### **Notes**

1. Plastic meets UL94 V0 at 1/8".

### Legal information

#### **DATA SHEET STATUS**

| DOCUMENT<br>STATUS <sup>(1)</sup> | PRODUCT<br>STATUS <sup>(2)</sup> | DEFINITION  |
|-----------------------------------|----------------------------------|---|
| Objective data sheet              | Development                      | This document contains data from the objective specification for product development. |
| Preliminary data sheet            | Qualification                    | This document contains data from the preliminary specification.                       |
| Product data sheet                | Production                       | This document contains the product specification.                                     |

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